

FEMTOCLOCKS™ CRYSTAL-TO-LVDS CLOCK GENERATOR

ICS844021I-01

GENERAL DESCRIPTION



The ICS844021I-01 is an Ethernet Clock Generator and a member of the HiPerClocks™ family of high performance devices from IDT. The ICS844021I-01 uses an 18pF parallel resonant crystal over the range of 24.5MHz – 34MHz. For Ethernet applications, a 25MHz crystal is used. The ICS844021I-01 has excellent <1ps phase jitter performance, over the 1.875MHz – 20MHz integration range. The ICS844021I-01 is packaged in a small 8-pin TSSOP, making it ideal for use in systems with limited board space.

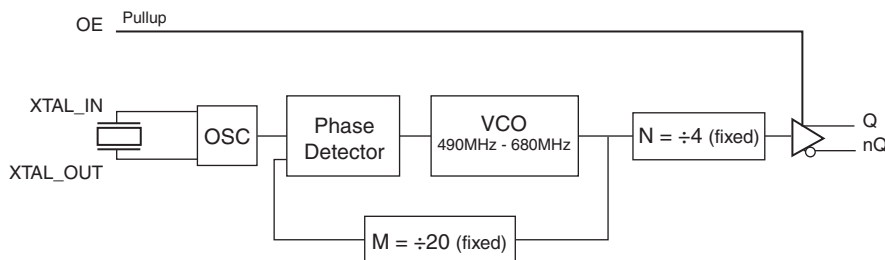
FEATURES

- One Differential LVDS output
- Crystal oscillator interface, 18pF parallel resonant crystal (24.5MHz – 34MHz)
- Output frequency range: 122.5MHz – 170MHz
- VCO range: 490MHz – 680MHz
- RMS phase jitter @ 125MHz, using a 25MHz crystal (1.875MHz – 20MHz): 0.32ps (typical) @ 3.3V
- 3.3V or 2.5V operating supply
- -40°C to 85°C ambient operating temperature
- Available in both standard (RoHS 5) and lead-free (RoHS 6) packages

COMMON CONFIGURATION TABLE - Gb ETHERNET

| Inputs | | | | Output Frequency (MHz) |
|-------------------------|----|---|--------------------------|------------------------|
| Crystal Frequency (MHz) | M | N | Multiplication Value M/N | |
| 25 | 20 | 4 | 5 | 125 |
| 26.666 | 20 | 4 | 5 | 133.33 |
| 33.33 | 20 | 4 | 5 | 166.66 |

BLOCK DIAGRAM



PIN ASSIGNMENT

| | | | |
|----------|---|---|-----|
| VDDA | 1 | 8 | VDD |
| GND | 2 | 7 | Q |
| XTAL_OUT | 3 | 6 | nQ |
| XTAL_IN | 4 | 5 | OE |

ICS844021I-01
8-Lead TSSOP

4.40mm x 3.0mm x 0.925mm
package body
G Package
Top View

The Preliminary Information presented herein represents a product in pre-production. The noted characteristics are based on initial product characterization and/or qualification. Integrated Device Technology, Incorporated (IDT) reserves the right to change any circuitry or specifications without notice.

TABLE 1. PIN DESCRIPTIONS

| Number | Name | Type | | Description |
|---------|----------------------|--------|--------|---|
| 1 | V _{DDA} | Power | | Analog supply pin. |
| 2 | GND | Power | | Power supply ground. |
| 3, 4 | XTAL_OUT, XTAL_IN | Input | | Crystal oscillator interface. XTAL_IN is the input, XTAL_OUT is the output. |
| 5 | OE | Input | Pullup | Output enable pin. When HIGH, Q/nQ output is active. When LOW, the Q/nQ output is in a high impedance state. LVCMOS/LVTTL interface levels. |
| 6, 7 | nQ, Q | Output | | Differential clock outputs. LVDS interface levels. |
| 8 | V _{DD} | Power | | Core supply pin. |

NOTE: *Pullup* refers to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|---------------------|-----------------------|-----------------|---------|---------|---------|-------|
| C _{IN} | Input Capacitance | | | 4 | | pF |
| R _{PULLUP} | Input Pullup Resistor | | | 51 | | kΩ |

ABSOLUTE MAXIMUM RATINGS

| | |
|--|---------------------------|
| Supply Voltage, V_{DD} | 4.6V |
| Inputs, V_I | -0.5V to $V_{DD} + 0.5$ V |
| Outputs, I_O (LVDS) | |
| Continuous Current | 10mA |
| Surge Current | 15mA |
| Package Thermal Impedance, θ_{JA} | 129.5°C/W (0 mps) |
| Storage Temperature, T_{STG} | -65°C to 150°C |

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 3A. POWER SUPPLY DC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------|-----------------------|-----------------|-----------------|---------|----------|-------|
| V_{DD} | Core Supply Voltage | | 3.135 | 3.3 | 3.465 | V |
| V_{DDA} | Analog Supply Voltage | | $V_{DD} - 0.08$ | 3.3 | V_{DD} | V |
| I_{DD} | Power Supply Current | | | 55 | | mA |
| I_{DDA} | Analog Supply Current | | | 8 | | mA |

TABLE 3B. POWER SUPPLY DC CHARACTERISTICS, $V_{DD} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------|-----------------------|-----------------|-----------------|---------|----------|-------|
| V_{DD} | Core Supply Voltage | | 2.375 | 2.5 | 2.625 | V |
| V_{DDA} | Analog Supply Voltage | | $V_{DD} - 0.08$ | 2.5 | V_{DD} | V |
| I_{DD} | Power Supply Current | | | 52 | | mA |
| I_{DDA} | Analog Supply Current | | | 8 | | mA |

TABLE 3C. LVCMOS/LVTTL DC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$ OR $2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------|--------------------|---|---------|---------|----------------|---------------|
| V_{IH} | Input High Voltage | $V_{DD} = 3.3V$ | 2 | | $V_{DD} + 0.3$ | V |
| | | $V_{DD} = 2.5V$ | 1.7 | | $V_{DD} + 0.3$ | V |
| V_{IL} | Input Low Voltage | $V_{DD} = 3.3V$ | -0.3 | | 0.8 | V |
| | | $V_{DD} = 2.5V$ | -0.3 | | 0.7 | V |
| I_{IH} | Input High Current | $V_{DD} = V_{IN} = 3.465V$ or $2.625V$ | | | 5 | μA |
| I_{IL} | Input Low Current | $V_{DD} = 3.465V$ or $2.625V$, $V_{IN} = 0V$ | -150 | | | μA |

TABLE 3D. LVDS DC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------------|-----------------------------|-----------------|---------|---------|---------|-------|
| V_{OD} | Differential Output Voltage | | | 400 | | mV |
| ΔV_{OD} | V_{OD} Magnitude Change | | | 10 | | mV |
| V_{OS} | Offset Voltage | | | 1.3 | | V |
| ΔV_{OS} | V_{OS} Magnitude Change | | | 10 | | mV |

NOTE: Please refer to Parameter Measurement Information for output information.

TABLE 3E. LVDS DC CHARACTERISTICS, $V_{DD} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------------|-----------------------------|-----------------|---------|---------|---------|-------|
| V_{OD} | Differential Output Voltage | | | 400 | | mV |
| ΔV_{OD} | V_{OD} Magnitude Change | | | 10 | | mV |
| V_{OS} | Offset Voltage | | | 1.2 | | V |
| ΔV_{OS} | V_{OS} Magnitude Change | | | 10 | | mV |

NOTE: Please refer to Parameter Measurement Information for output information.

TABLE 4. CRYSTAL CHARACTERISTICS

| Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|------------------------------------|-----------------|-------------|---------|---------|---------------|
| Mode of Oscillation | | Fundamental | | | |
| Frequency | | 24.5 | | 34 | MHz |
| Equivalent Series Resistance (ESR) | | | | 50 | Ω |
| Shunt Capacitance | | | | 7 | pF |
| Drive Level | | | | 100 | μW |

TABLE 5A. AC CHARACTERISTICS, $V_{DD} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------------------|---------------------------------------|--|---------|---------|---------|-------|
| f_{OUT} | Output Frequency | | 122.5 | | 170 | MHz |
| $f_{jit}(\emptyset)$ | RMS Phase Jitter (Random); NOTE 1 | 125MHz @ Integration Range: 1.875MHz - 20MHz | | 0.32 | | ps |
| | | 133.33MHz @ Integration Range: 1.875MHz - 20MHz | | TBD | | ps |
| | | 166.66MHz @ Integration Range: 1.875MHz - 20MHz | | TBD | | ps |
| t_R / t_F | Output Rise/Fall Time | 20% to 80% | | 300 | | ps |
| odc | Output Duty Cycle | | | 50 | | % |

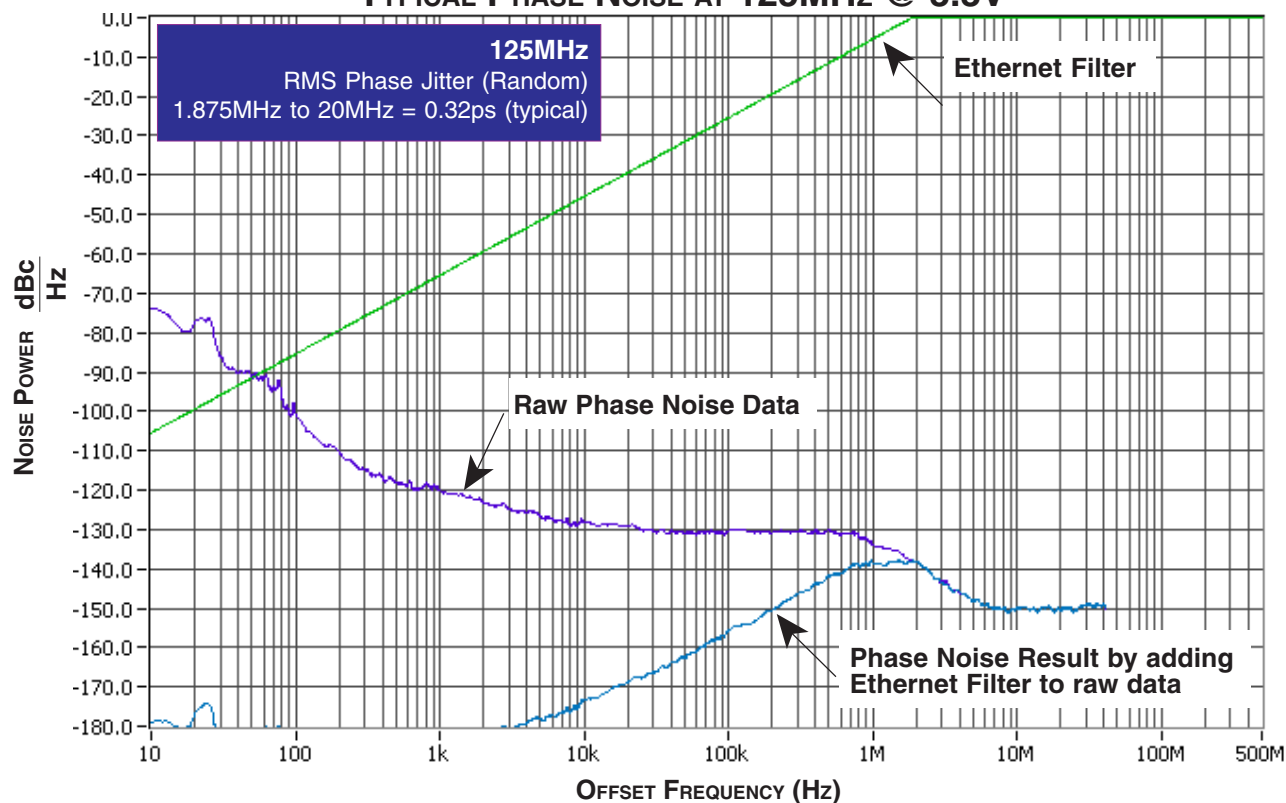
NOTE 1: Please refer to the Phase Noise Plots following this section.

TABLE 5B. AC CHARACTERISTICS, $V_{DD} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ TO 85°C

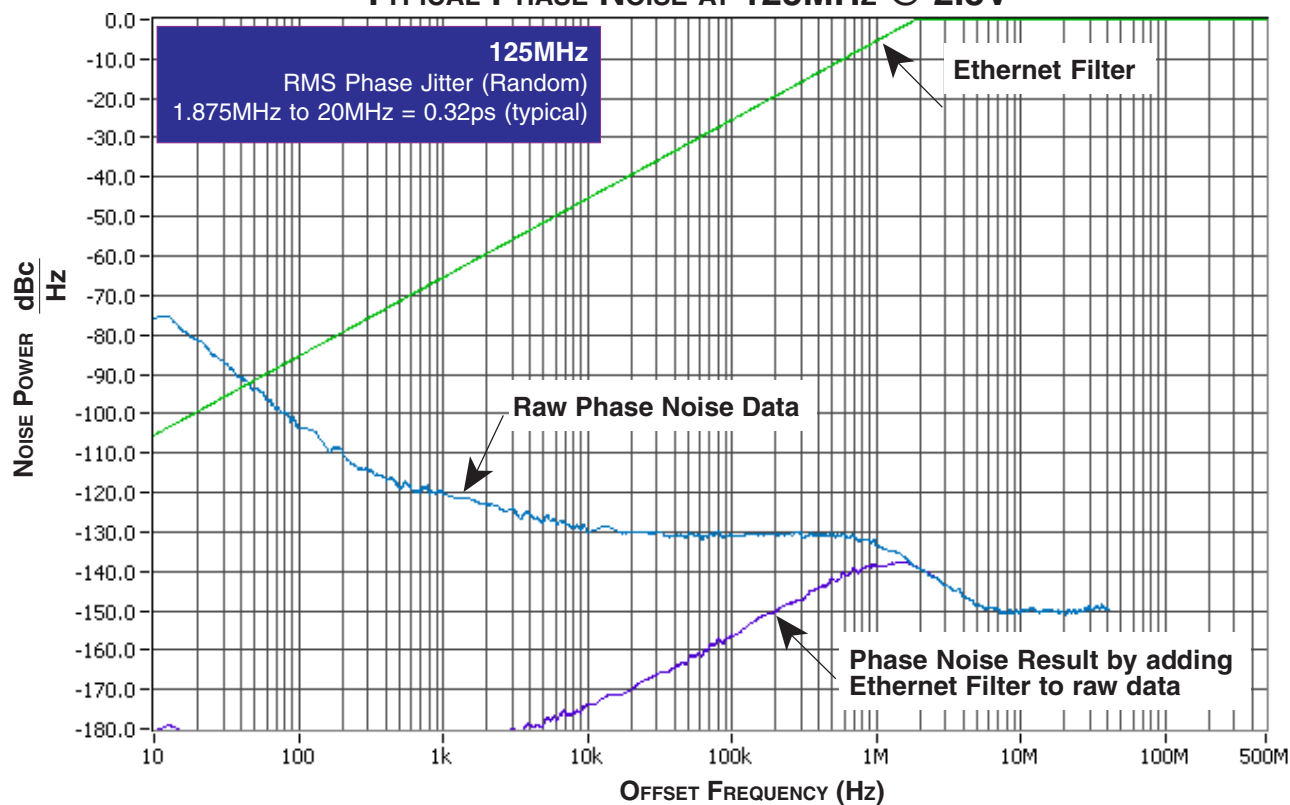
| Symbol | Parameter | Test Conditions | Minimum | Typical | Maximum | Units |
|----------------------|---------------------------------------|--|---------|---------|---------|-------|
| f_{OUT} | Output Frequency | | 122.5 | | 170 | MHz |
| $f_{jit}(\emptyset)$ | RMS Phase Jitter (Random); NOTE 1 | 125MHz @ Integration Range: 1.875MHz - 20MHz | | 0.31 | | ps |
| | | 133.33MHz @ Integration Range: 1.875MHz - 20MHz | | TBD | | ps |
| | | 166.66MHz @ Integration Range: 1.875MHz - 20MHz | | TBD | | ps |
| t_R / t_F | Output Rise/Fall Time | 20% to 80% | | 320 | | ps |
| odc | Output Duty Cycle | | | 50 | | % |

NOTE 1: Please refer to the Phase Noise Plots following this section.

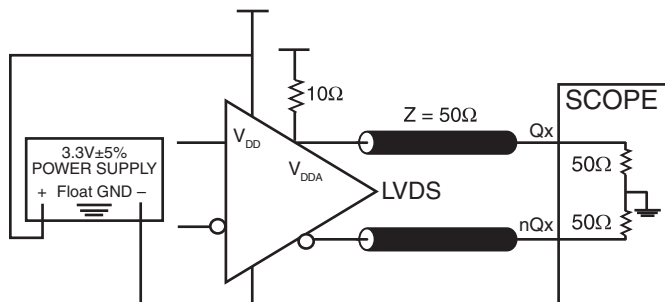
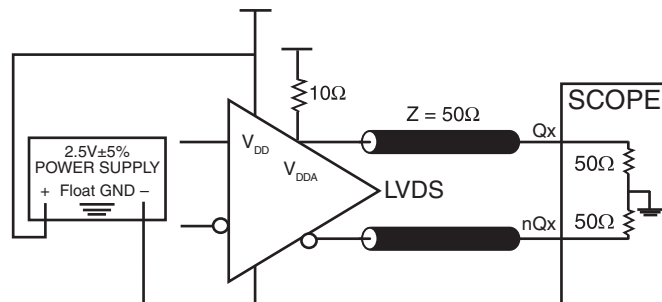
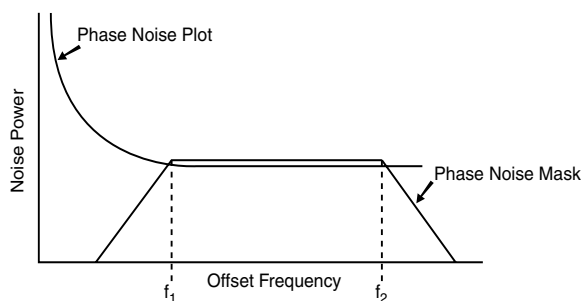
TYPICAL PHASE NOISE AT 125MHz @ 3.3V



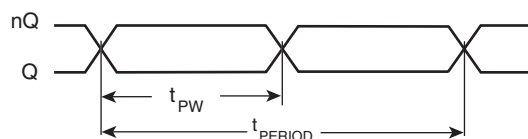
TYPICAL PHASE NOISE AT 125MHz @ 2.5V



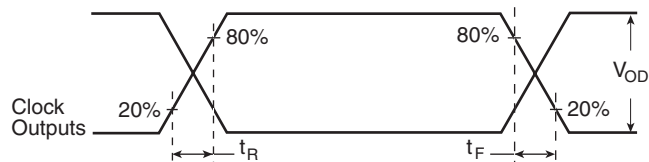
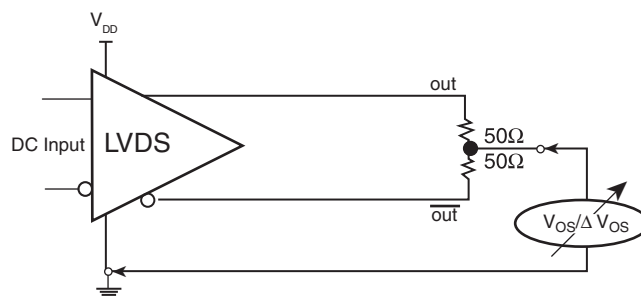
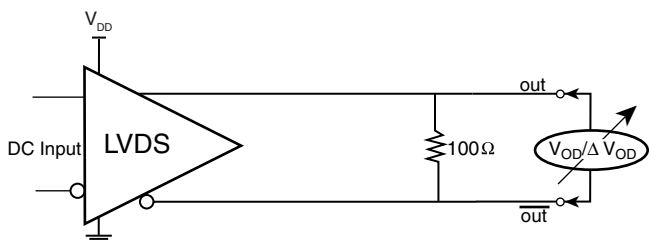
PARAMETER MEASUREMENT INFORMATION


LVDS 3.3V OUTPUT LOAD AC TEST CIRCUIT

LVDS 2.5V OUTPUT LOAD AC TEST CIRCUIT


$$\text{RMS Jitter} = \sqrt{\text{Area Under the Masked Phase Noise Plot}}$$

RMS PHASE JITTER


$$\text{odc} = \frac{t_{PW}}{t_{PERIOD}} \times 100\%$$

OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD

OUTPUT RISE/FALL TIME

OFFSET VOLTAGE SETUP

DIFFERENTIAL OUTPUT VOLTAGE SETUP

APPLICATION INFORMATION

POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The ICS844021I-01 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{DD} and V_{DDA} should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. *Figure 1* illustrates how a 10Ω resistor along with a $10\mu\text{F}$ and a $.01\mu\text{F}$ bypass capacitor should be connected to each V_{DDA} pin.

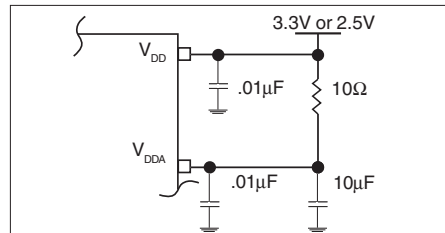


FIGURE 1. POWER SUPPLY FILTERING

CRYSTAL INPUT INTERFACE

The ICS844021I-01 has been characterized with 18pF parallel resonant crystals. The capacitor values, C1 and C2, shown in *Figure 2* below were determined using a 25MHz, 18pF parallel

resonant crystal and were chosen to minimize the ppm error. The optimum C1 and C2 values can be slightly adjusted for different board layouts.

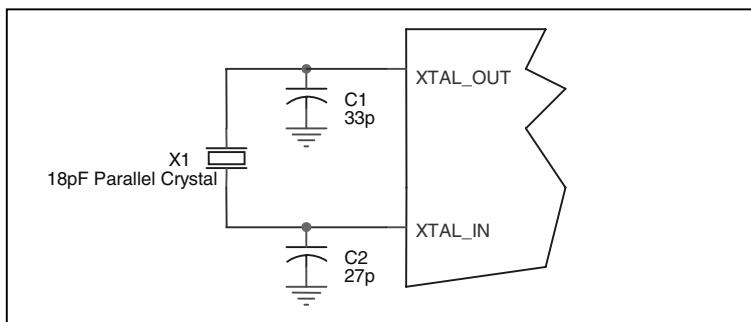


FIGURE 2. CRYSTAL INPUT INTERFACE

LVC MOS TO XTAL INTERFACE

The XTAL_IN input can accept a single-ended LVC MOS signal through an AC coupling capacitor. A general interface diagram is shown in *Figure 3*. The XTAL_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVC MOS inputs, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires that the output impedance of the driver (R_o) plus the

series resistance (R_s) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of two ways. First, R_1 and R_2 in parallel should equal the transmission line impedance. For most 50Ω applications, R_1 and R_2 can be 100Ω. This can also be accomplished by removing R_1 and making R_2 50Ω.

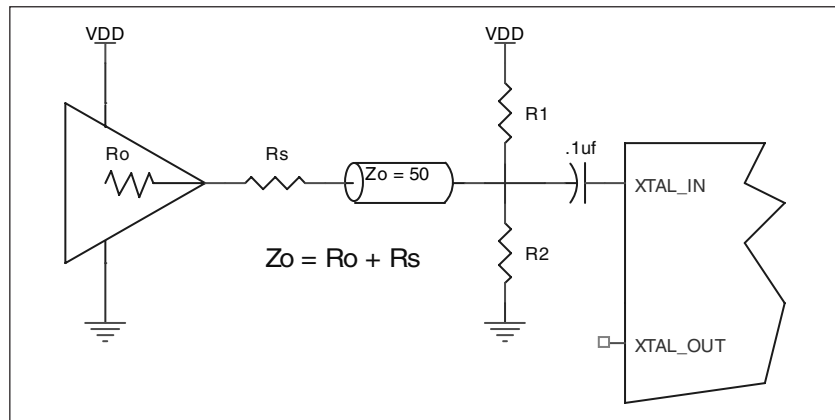


FIGURE 3. GENERAL DIAGRAM FOR LVC MOS DRIVER TO XTAL INPUT INTERFACE

3.3V, 2.5V LVDS DRIVER TERMINATION

A general LVDS interface is shown in *Figure 4*. In a 100Ω differential transmission line environment, LVDS drivers require a matched load termination of 100Ω across near

the receiver input. For a multiple LVDS outputs buffer, if only partial outputs are used, it is recommended to terminate the unused outputs.

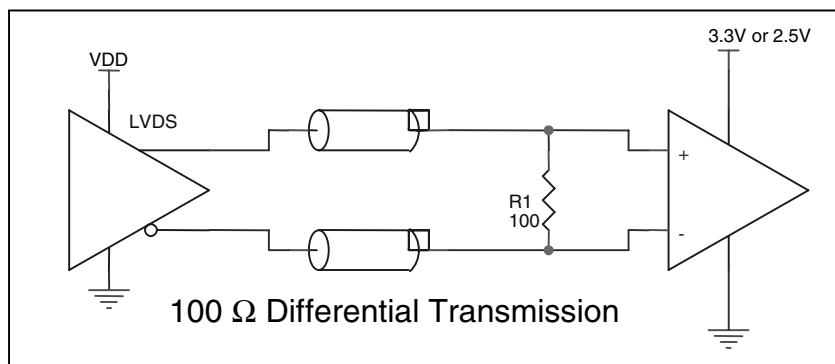


FIGURE 4. TYPICAL LVDS DRIVER TERMINATION

POWER CONSIDERATIONS

This section provides information on power dissipation and junction temperature for the ICS844021I-01. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS844021I-01 is the sum of the core power plus the analog plus the power dissipated in the load(s).

The following is the power dissipation for $V_{DD} = 3.3V + 5\% = 3.465V$, which gives worst case results.

- Power (core)_{MAX} = $V_{DD_MAX} * (I_{DD_MAX} + I_{DDA_MAX}) = 3.465V * (55mA + 8mA) = \mathbf{218.3mW}$

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS™ devices is 125°C.

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_total + T_A$

T_j = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 129.5°C/W per Table 6 below.

Therefore, T_j for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ\text{C} + 0.218\text{W} * 129.5^\circ\text{C/W} = 113.2^\circ\text{C}. \text{ This is below the limit of } 125^\circ\text{C}.$$

This calculation is only an example. T_j will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

TABLE 6. THERMAL RESISTANCE θ_{JA} FOR 8-LEAD TSSOP, FORCED CONVECTION

| θ_{JA} by Velocity (Meters per Second) | | | |
|---|-----------|-----------|-----------|
| | 0 | 1 | 2.5 |
| Multi-Layer PCB, JEDEC Standard Test Boards | 129.5°C/W | 125.5°C/W | 123.5°C/W |

RELIABILITY INFORMATION

TABLE 7. θ_{JA} VS. AIR FLOW TABLE FOR 8 LEAD TSSOP

| θ_{JA} by Velocity (Meters per Second) | | | |
|---|-----------|-----------|-----------|
| | 0 | 1 | 2.5 |
| Multi-Layer PCB, JEDEC Standard Test Boards | 129.5°C/W | 125.5°C/W | 123.5°C/W |

TRANSISTOR COUNT

The transistor count for ICS844021I-01 is: 2533

PACKAGE OUTLINE - G SUFFIX FOR 8 LEAD TSSOP

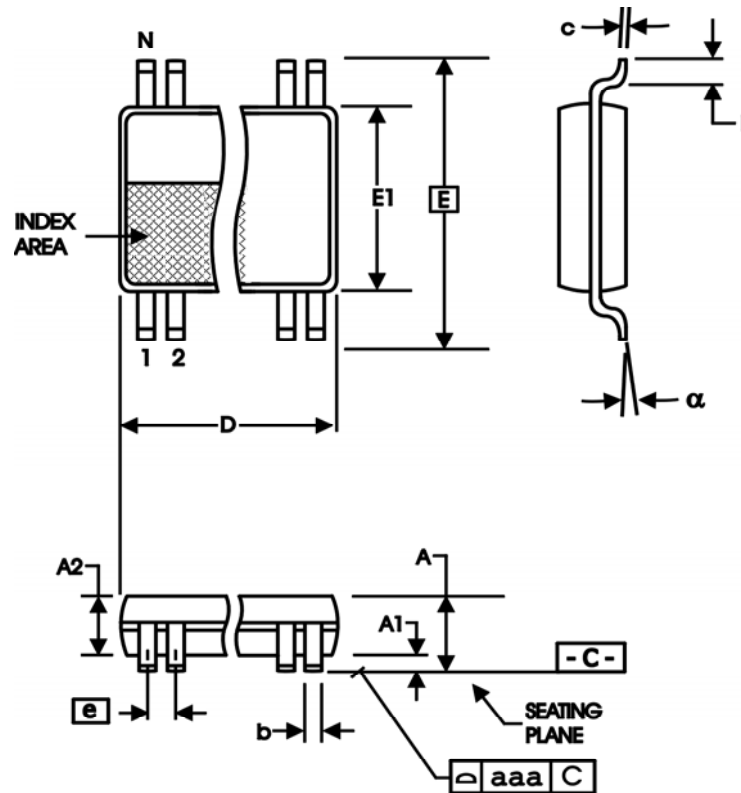


TABLE 8. PACKAGE DIMENSIONS

| SYMBOL | Millimeters | |
|----------|-------------|---------|
| | Minimum | Maximum |
| N | 8 | |
| A | -- | 1.20 |
| A1 | 0.05 | 0.15 |
| A2 | 0.80 | 1.05 |
| b | 0.19 | 0.30 |
| c | 0.09 | 0.20 |
| D | 2.90 | 3.10 |
| E | 6.40 BASIC | |
| E1 | 4.30 | 4.50 |
| e | 0.65 BASIC | |
| L | 0.45 | 0.75 |
| α | 0° | 8° |
| aaa | -- | 0.10 |

Reference Document: JEDEC Publication 95, MO-153

TABLE 9. ORDERING INFORMATION

| Part/Order Number | Marking | Package | Shipping Packaging | Temperature |
|--------------------|---------|--------------------------|--------------------|---------------|
| ICS844021BGI-01 | 2BI01 | 8 lead TSSOP | tube | -40°C to 85°C |
| ICS844021BGI-01T | 2BI01 | 8 lead TSSOP | 2500 tape & reel | -40°C to 85°C |
| ICS844021BGI-01LF | BI01L | 8 lead "Lead-Free" TSSOP | tube | -40°C to 85°C |
| ICS844021BGI-01LFT | BI01L | 8 lead "Lead-Free" TSSOP | 2500 tape & reel | -40°C to 85°C |

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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